

Vishay Semiconductors

High Performance Schottky Rectifiers, 2 x 20 A





ე 5 Common 0310 Anode cathode Anode

common

cathode

02

VS-48CTQ060S-M3

VS-48CTQ060-1-M3

cathode Anode

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Common

Anode

d 3

common

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Q2

PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V _R	60 V					
V _F at I _F	0.58 V					
I _{RM} typ.	89 mA at 125 °C					
T _J max.	150 °C					
E _{AS}	13 mJ					
Package	D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES

150 °C T_J operation

- Center tap configuration
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	A			
V _{RRM}		60	V			
I _{FSM}	t _p = 5 μs sine	1000	A			
V _F	20 A_{pk} , T_J = 125 °C (per leg)	0.58	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-48CTQ060S-M3 VS-48CTQ060-1-M3	UNITS		
Maximum DC reverse voltage	V _R	60	N .		
Maximum working peak reverse voltage	V _{RWM}	00	V		

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER		SYMBOL	TEST CONE	DITIONS	VALUES	UNITS		
Maximum average	per leg				20			
forward current See fig. 5 per device		I _{F(AV)}	50 % duty cycle at T_C = 111 °C, rectangular waveform		40	А		
Maximum peak one cycle	-repetitive surge current per leg		5 µs sine or 3 µs rect. pulse Following any rated load		1000	~		
non-repetitive surge curren See fig. 7			10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	260			
Non-repetitive avalanche e	nergy per leg	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 1.50 \text{ A}, L = 11$	I.5 mH	13	mJ		
Repetitive avalanche currer	nt per leg	I _{AR}	Current decaying linearly to zero Frequency limited by T_J maxim		1.50	А		

ELECTRICAL SPECIFICATION	S				
PARAMETER	SYMBOL	TEST CO	ONDITIONS	VALUES	UNITS
		20 A	T ₁ = 25 °C	0.61	
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	40 A	1j=25 C	0.83	V
See fig. 1	VFM (1)	20 A	T,I = 125 °C	0.58	V
		40 A	-1j = 125 G	0.75	
Maximum rayaraa laakaga ayrrant par lag	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated V _B	2	m۸
Maximum reverse leakage current per leg	IRM \''	T _J = 125 °C	V _R = naleu V _R	140	140 mA
Typical reverse leakage current	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = Rated V _R	89	mA
Threshold Voltage	V _{F(TO)}	T T movimum		0.37	V
Forward slope resistance	r _t	$T_J = T_J$ maximum		8.26	mΩ
Maximum junction capacitance per leg	CT	V _R = 5 V _{DC} (test signal rang	ge 100 kHz to 1 MHz), 25 °C	1220	pF
Typical series inductance per leg	L _S	Measured lead to lead 5 m	m from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECH	ANICAL S	PECIFIC	ATIONS			
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and stor temperature range	rage	T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistance, unction to case per leg		Р	DC aparetien	2.0		
Maximum thermal resistance, junction to case per package		R _{thJC} I	DC operation	1.0	°C/W	
Typical thermal resistance, case to heatsink			Mounting surface, smooth and greased	0.50		
Approvimete weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	6 (5) kgf · cm	
Mounting torque	maximum			12 (10)	(lbf · in)	
Marking daviaa			Case style D ² PAK (TO-263AB)	D-263AB) 48CTQ060S		
Marking device			Case style TO-262AA	48CTQ	060-1	

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T_{.1} = 150 °C

= 125 °C

T_{.1} = 100

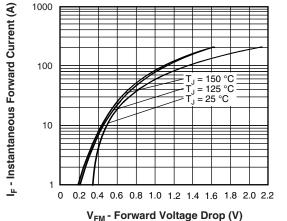
 $T_{1} = 75 \,^{\circ}C$

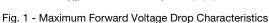
T_{.1} = 50 °C

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. T_J = 25 °C

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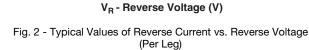


C_T - Junction Capacitance (pF)

100 L

10

20



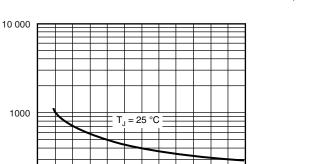
30

40

50

60

20



40

50

60

1000

100

10

1

0.1

0.01

0.001

0

I_R - Reverse Current (mA)



30

V_R - Reverse Voltage (V)

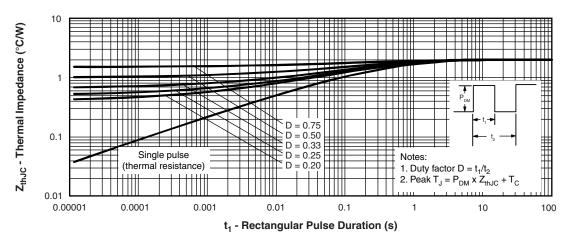


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

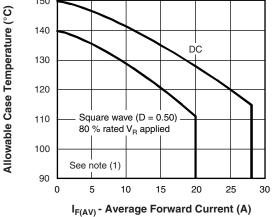
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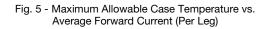
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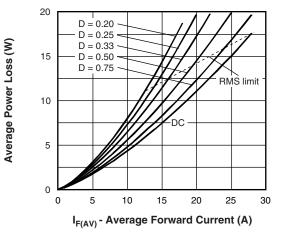
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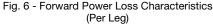


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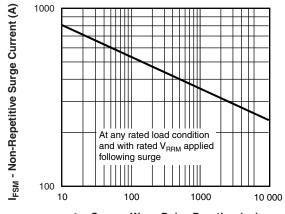




Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

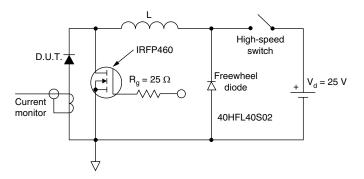


Fig. 8 - Unclamped Inductive Test Circuit

Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
- Pd = forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}/D$) (see fig. 6); Pd_{REV} = inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 10 V

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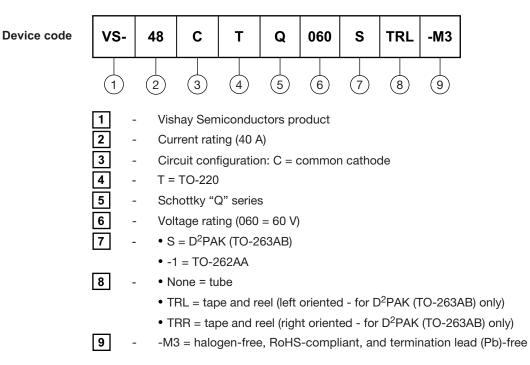
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ORDERING INFORMATION TABLE



ORDERING INFORMATION						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-48CTQ060S-M3	50	1000	Antistatic plastic tubes			
VS-48CTQ060STRR-M3	800	800	13" diameter reel			
VS-48CTQ060STRL-M3	800	800	13" diameter reel			
VS-48CTQ060-1-M3	50	1000	Antistatic plastic tubes			

	LINKS TO RELAT	ED DOCUMENTS
Dimensions	D ² PAK (TO-263AB)	www.vishay.com/doc?96164
Dimensions	TO-262AA	www.vishay.com/doc?96165
Port marking information	D ² PAK (TO-263AB)	www.vishay.com/doc?95444
Part marking information	TO-262AA	www.vishay.com/doc?95443
Packaging information		www.vishay.com/doc?96424

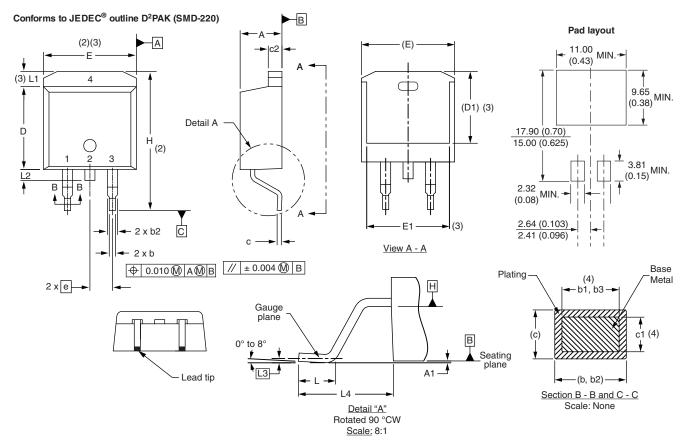


Outline Dimensions

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DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES	OTES SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100) BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
с	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010) BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

(7) Outline conforms to JEDEC® outline TO-263AB

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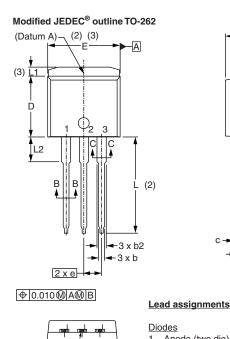


Outline Dimensions

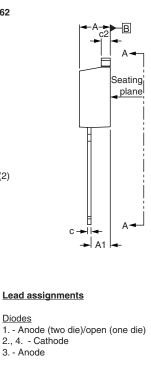
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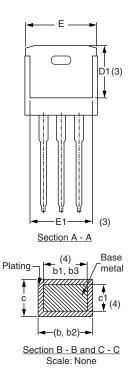
TO-262

DIMENSIONS in millimeters and inches



Lead tip





CVMDOI	MILLIN	IETERS	INC	INCHES			
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
А	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
E	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54	2.54 BSC		BSC			
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.36	3.71	0.132	0.146			

3. - Anode

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are

measured at the outmost extremes of the plastic body ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1 (4) Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum), D1 (minimum) and L2 where dimensions derived the actual package outline

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